



High-end Power Semiconductor Manufacturer

ZK3500A 1100-2000V Fast Recovery Diode

- Low switching losses
- Low reverse recovery charge High
- power cycling capability



| | | | | | | |
|---------------------------------|------------|-----------|------|---------------|------|------|
| Average forward current | | I_{FAV} | | 3560 A | | |
| Repetitive peak reverse voltage | | V_{RRM} | | 1100 – 2000 V | | |
| Reverse recovery time | | t_{rr} | | 7.00 μ s | | |
| V_{RRM} , V | 1100 | 1200 | 1400 | 1600 | 1800 | 2000 |
| Voltage code | 11 | 12 | 14 | 16 | 18 | 20 |
| T_j , °C | – 60 – 150 | | | | | |

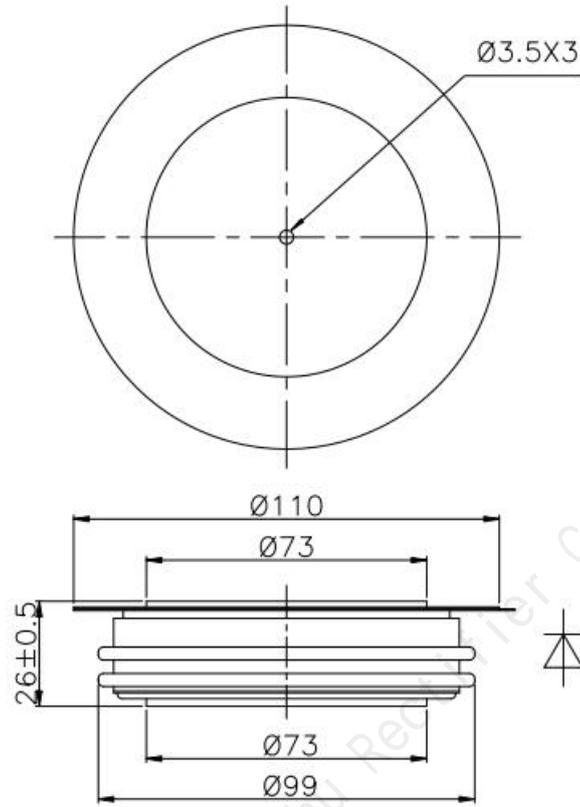
MAXIMUM ALLOWABLE RATINGS

| Symbols and parameters | | Units | Values | Test conditions | |
|------------------------|----------------------------------|-------------------|--------------|--|---|
| ON-STATE | | | | | |
| I_{FAV} | Average forward current | A | 3560 | $T_c=85$ °C; Double side cooled; 180° half-sine wave; 50 Hz | |
| I_{FSM} | Surge forward current | kA | 44.0 | $T_j=T_{j\max}$ | 180° half-sine wave; $t_p=10$ ms; $V_R=0.6V_{RRM}$ |
| I^2t | Safety factor | $A^2s \cdot 10^3$ | 9680 | $T_j=T_{j\max}$ | 180° half-sine wave; $t_p=10$ ms; $V_R=0.6V_{RRM}$ |
| BLOCKING | | | | | |
| V_{RRM} | Repetitive peak reverse voltages | V | 1100–2000 | $t_p=10$ ms | |
| V_R | Reverse continuous voltages | V | $0.6V_{RRM}$ | $T_j=T_{j\max}$ | |
| THERMAL | | | | | |
| T_{stg} | Storage temperature | °C | –40–160 | | |
| T_j | Operating junction temperature | °C | –60 –150 | | |
| MECHANICAL | | | | | |
| F | Mounting force | kN | 35 – 47 | | |

CHARACTERISTICS

| Symbols and parameters | | Units | Values | Conditions | |
|------------------------|---|---------------------------|--------|---|--------------------|
| ON-STATE | | | | | |
| V_{FM} | Peak forward voltage, max | V | 3.00 | $T_j=25\text{ }^\circ\text{C}; I_{TM}=5000\text{A}, F=40.0\text{kN}$ | |
| $V_{F(TO)}$ | Forward threshold voltage, max | V | 0.95 | $T_j=T_{j\text{ max}}$ | |
| r_T | Forward slope resistance, max | m Ω | 0.10 | | |
| BLOCKING | | | | | |
| I_{RRM} | Repetitive peak reverse current, max | mA | 240 | $T_j=T_{j\text{ max}};$ $V_R=V_{RRM}$ | |
| SWITCHING | | | | | |
| Q_{rr} | Total recovered charge, max | μC | 1300 | $I_{TM}=2000\text{A}, t_p=1000\mu\text{s},$ $-di/dt=20\text{A}/\mu\text{s},$ $V_R=50\text{V}$ | |
| t_{rr} | Reverse recovery time ¹⁾ , max | μs | 7.00 | | |
| THERMAL | | | | | |
| R_{thjc} | Thermal resistance, junction to case, max | $^\circ\text{C}/\text{W}$ | 0.0100 | Clamping force 40.0kN | Double side cooled |
| R_{thck} | Thermal resistance, case to heatsink, max | $^\circ\text{C}/\text{W}$ | 0.0030 | Clamping force 40.0kN | Double side cooled |
| MECHANICAL | | | | | |
| w | Weight, max | g | 1100 | | |

OVERALL DIMENSIONS



ZT80

All dimensions in millimeters